

# PC904

## Built-in Voltage Detection Circuit Type Photocoupler

※Lead forming type (I type) and taping reel type (P type) are also available. (PC904I/PC904P) (Page 656)

### ■ Features

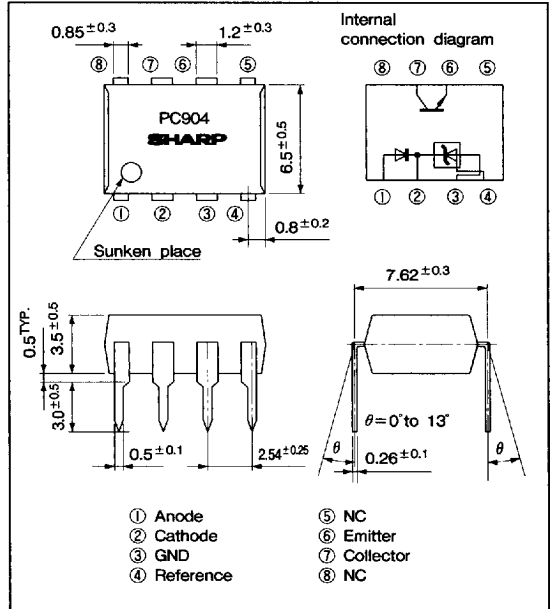
1. Built-in voltage detection circuit
2. High isolation voltage between input and output ( $V_{iso} : 5\,000V_{rms}$ )
3. Standard 8-pin dual-in-line package
4. Recognized by UL, file No. E64380

### ■ Applications

1. Switching power supplies

### ■ Outline Dimensions

(Unit : mm)



### ■ Absolute Maximum Ratings

( $T_a = 25^\circ\text{C}$ )

	Parameter	Symbol	Rating	Unit
Input	Anode current	$I_A$	50	mA
	Anode voltage	$V_A$	30	V
	Reference input current	$I_{REF}$	10	mA
	Power dissipation	P	250	mW
Output	Collector-emitter voltage	$V_{CEO}$	35	V
	Emitter-collector voltage	$V_{ECO}$	6	V
	Collector current	$I_C$	50	mA
	Collector power dissipation	$P_C$	150	mW
	Total power dissipation	$P_{tot}$	350	mW
	*1 Isolation voltage	$V_{iso}$	5 000	$V_{rms}$
	Operating temperature	$T_{opr}$	-25 to +85	$^\circ\text{C}$
	Storage temperature	$T_{stg}$	-40 to +125	$^\circ\text{C}$
	*2 Soldering temperature	$T_{sol}$	260	$^\circ\text{C}$

\*1 40 to 60%RH AC for 1 minute

\*2 For 10 seconds

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"In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that occur in equipment using any of SHARP's devices, shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest version of the device specification sheets before using any SHARP's device."

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# Electro-optical Characteristics

(Ta = 25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	Fig.
Input	Reference voltage	$V_{REF}$	$V_K = V_{REF}, I_A = 10\text{mA}$	2.40	2.495	2.60	V	1
	*3 Temperature change in reference voltage	$V_{REF(\text{dev})}$	$V_K = V_{REF}, I_A = 10\text{mA}, T_a = -25 \text{ to } +85^\circ\text{C}$	—	8	40	mV	1
	Voltage variation ratio in reference voltage	$\Delta V_{REF}/\Delta V_A$	$I_A = 10\text{mA}, \Delta V_A = 30\text{V} - V_{REF}$	—	-1.4	-5	mV/V	2
	Reference input current	$I_{REF}$	$I_A = 10\text{mA}, R_3 = 10\text{k}\Omega$	—	2	10	$\mu\text{A}$	3
	*4 Temperature change in reference input current	$I_{REF(\text{dev})}$	$I_A = 10\text{mA}, R_3 = 10\text{k}\Omega, T_a = -25 \text{ to } +85^\circ\text{C}$	—	0.4	3	$\mu\text{A}$	3
	Minimum drive current	$I_{MIN}$	$V_K = V_{REF}$	—	1	2	mA	1
	OFF-state anode current	$I_{OFF}$	$V_A = 30\text{V}, V_{REF} = \text{GND}$	—	0.1	2	$\mu\text{A}$	4
Output	Anode-cathode forward voltage	$V_F$	$V_K = V_{REF}, I_A = 10\text{mA}$	—	1.2	1.4	V	1
	Collector dark current	$I_{CEO}$	$V_{CE} = 35\text{V}$	—	$1 \times 10^{-9}$	$1 \times 10^{-7}$	A	5
Transfer characteristics	*5 Current transfer ratio	CTR	$V_K = V_{REF}, I_A = 5\text{mA}, V_{CE} = 5\text{V}$	50	—	600	%	6
	Collector-emitter saturation voltage	$V_{CE(\text{sat})}$	$V_K = V_{REF}, I_A = 10\text{mA}, I_C = 1\text{mA}$	—	0.1	0.2	V	6
	Isolation resistance	$R_{ISO}$	40 to 60%RH, DC500V	$5 \times 10^{10}$	$1 \times 10^{11}$	—	$\Omega$	—
	Floating capacitance	$C_f$	$V = 0, f = 1\text{kHz}$	—	0.6	1.0	pF	—

\*3  $V_{REF(\text{dev})} = V_{REF(\text{MAX.})} - V_{REF(\text{MIN.})}$ \*4  $I_{REF(\text{dev})} = I_{REF(\text{MAX.})} - I_{REF(\text{MIN.})}$ \*5  $\text{CTR} = I_C/I_A \times 100$  (%)

Classification table of current transfer ratio is shown below. (4 models)

Model No.	Rank mark	CTR (%)
PC904A	A	50 to 150
PC904B	B	100 to 300
PC904C	C	250 to 600
PC904	A, B or C	50 to 600

## Test Circuit

Fig. 1

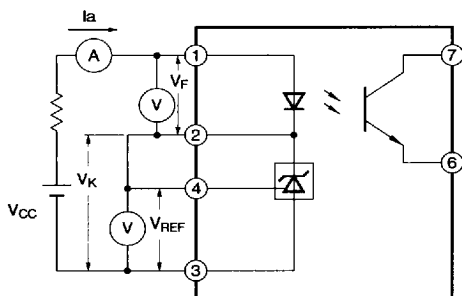


Fig. 2

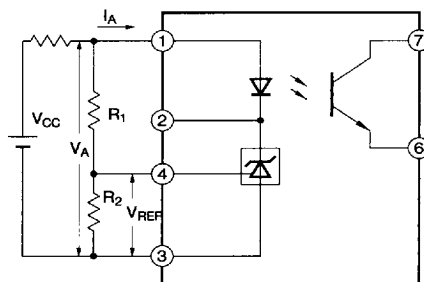


Fig. 3

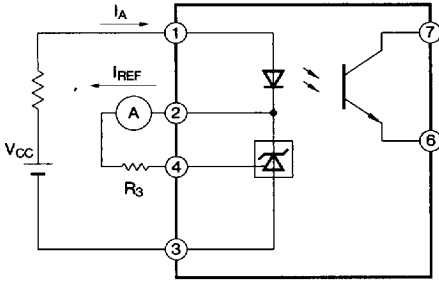


Fig. 4

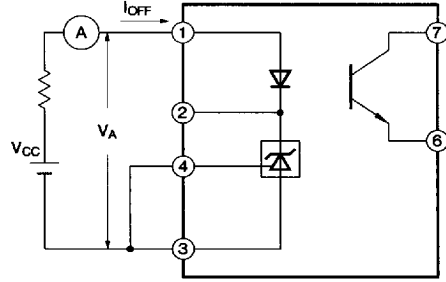


Fig. 5

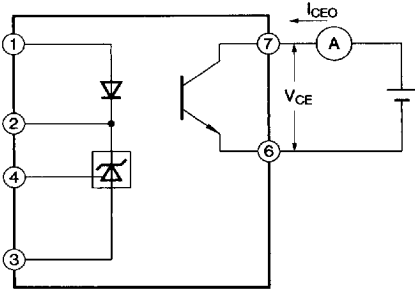


Fig. 6

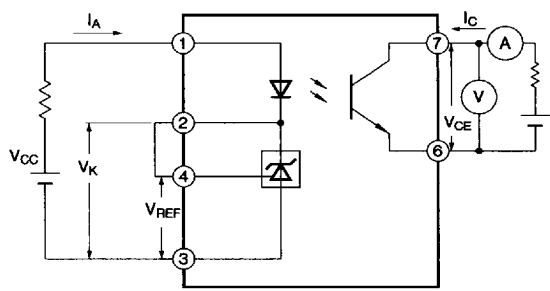


Fig. 7 Anode Current vs. Ambient Temperature

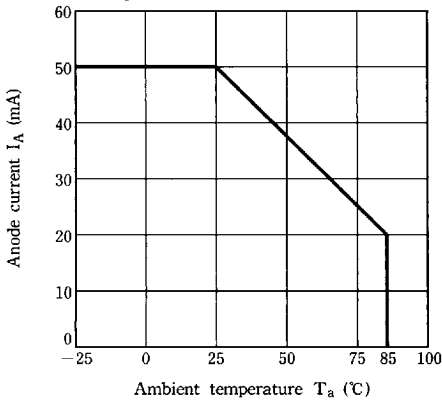
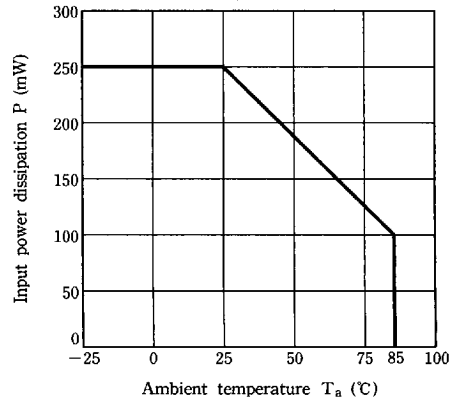
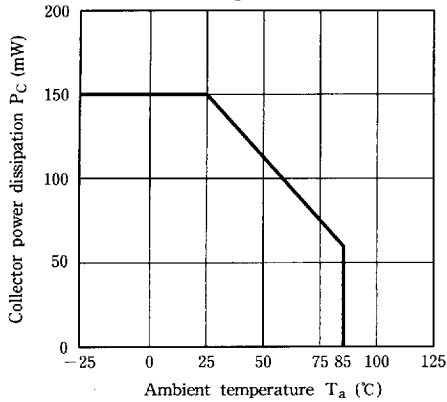
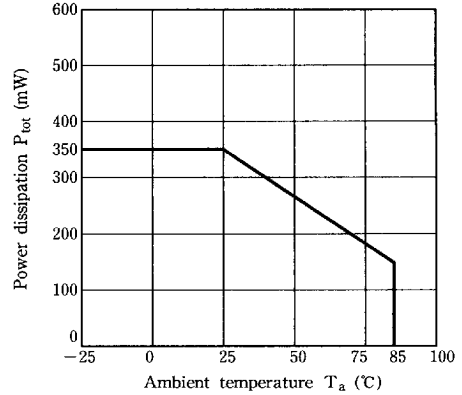
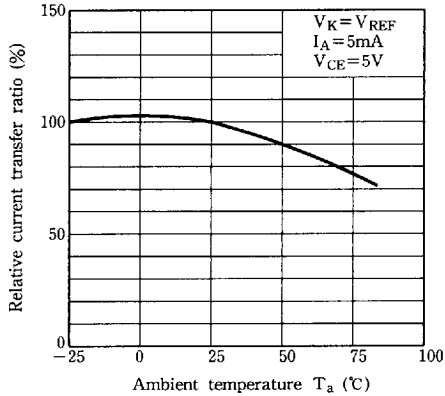
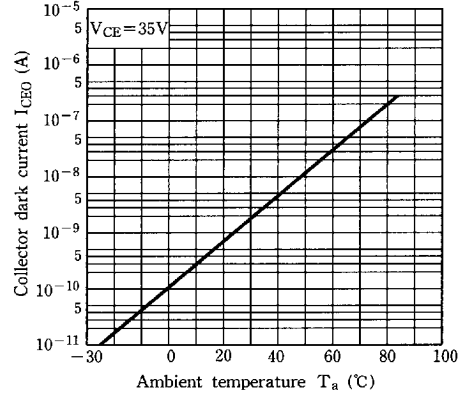
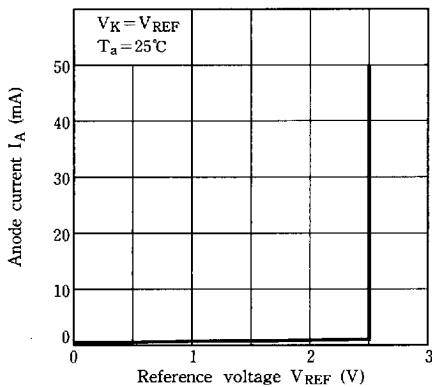
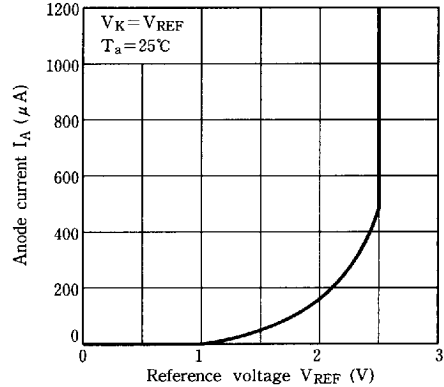
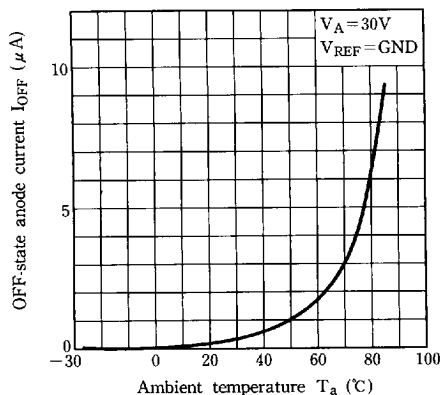
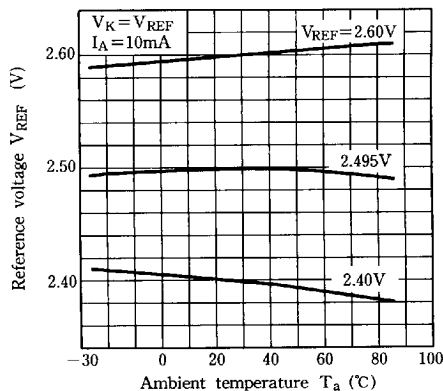
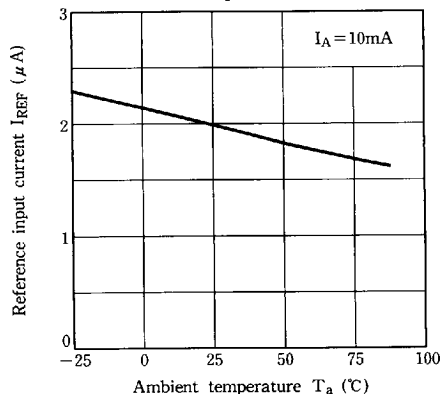
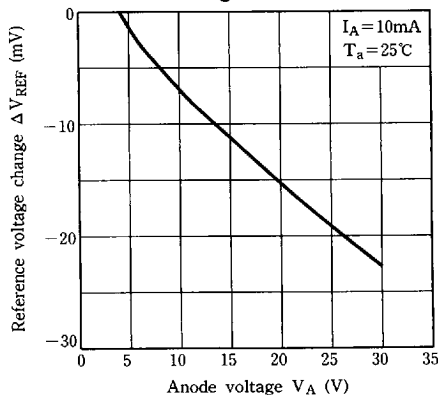
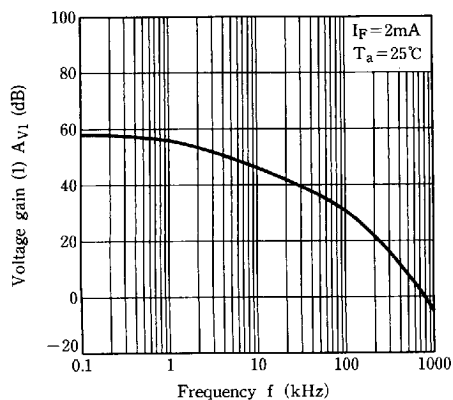
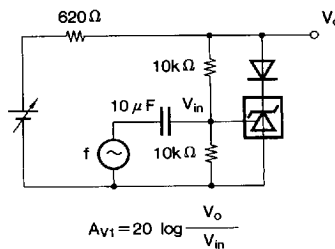
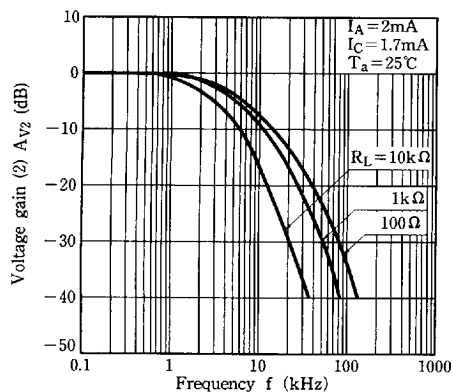
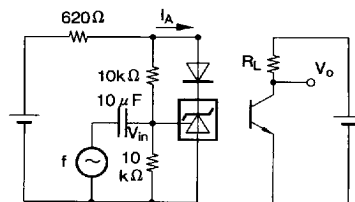
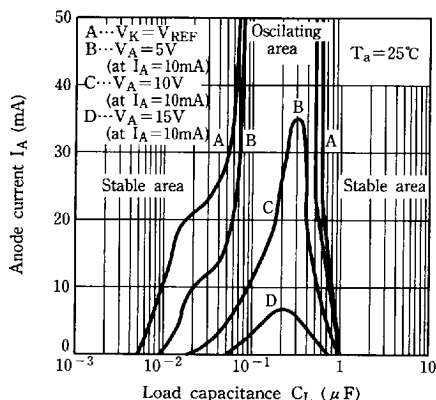
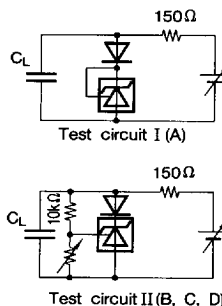
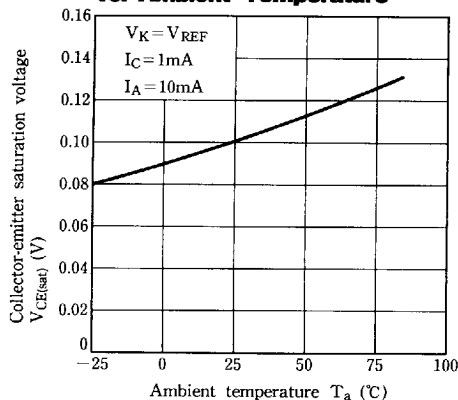
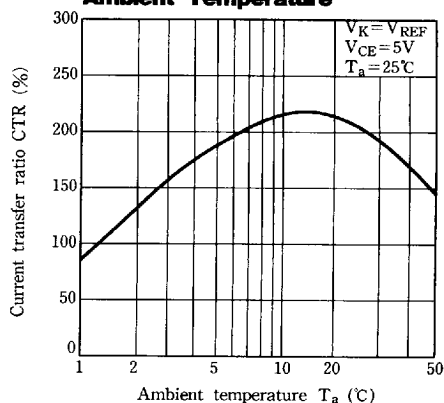


Fig. 8 Input Power Dissipation vs. Ambient Temperature



**Fig. 9 Collector Power Dissipation vs. Ambient Temperature****Fig.10 Power Dissipation vs. Ambient Temperature****Fig.11 Relative Current Transfer Ratio vs. Ambient Temperature****Fig.12 Collector Dark Current vs. Ambient Temperature****Fig.13-a Anode Current vs. Reference Voltage****Fig.13-b Anode Current vs. Reference Voltage**

**Fig.14 OFF-state Anode Current vs. Ambient Temperature****Fig.15 Reference Voltage Change vs. Ambient Temperature****Fig.16 Reference Input Current vs. Ambient Temperature****Fig.17 Reference Voltage Change vs. Anode Voltage****Fig.18-a Voltage Gain (1) vs. Frequency****Test Circuit for Voltage Gain (1) vs. Frequency**

**Fig.18-b Voltage Gain (2) vs. Frequency****Test Circuit for Voltage Gain (2) vs. Frequency****Fig.19 Anode Current vs. Load Capacitance****Test Circuit for Anode Current vs. Load Capacitance****Fig.20 Collector-emitter Saturation Voltage vs. Ambient Temperature****Fig.21 Current Transfer Ratio vs. Ambient Temperature****■ Precautions for Use**

Handle this product the same as with other integrated circuits against static electricity.

- As for other general cautions, refer to the chapter "Precautions for Use" (Page 78 to 93).